## NSN 5961-01-346-7892

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-346-7892 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.810 inches **Overall Height:** 0.155 inches **Overall Width:** 0.745 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 25.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open and 50.0 collector to emitter voltage, dc with base short-circuited to emitter **Current Rating Per Characteristic:** 1.50 amperes source cutoff current **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 ribbon and 2 flange Shelf Life: N/a **Unit Of Measure: Demilitarization:** No